#### **Application Data Sheet**

### **Application Information**

**Application Type::** 

Regular

Subject Matter::

Utility

Suggested Classification::

256/287

Suggested Group Art Unit::

2820

CD-ROM or CD-R?

None

Title::

Drain Extended MOS Transistor with Improved

**Breakdown Robustness** 

Attorney Docket Number::

TI-34637

Request for Early Publication?:: No

Request for Non-Publication?:: No

Suggested Drawing Figure::

3b

Total Drawing Sheets::

5

Small Entity::

No

Petition included?::

No

Secrecy Order in Parent Appl.?:: No

## **Applicant Information**

Applicant Authority type::

Inventor

**Primary Citizenship Country:** 

US

Status::

**Full Capacity** 

Given Name::

Sameer

Middle Name::

Р.

Family Name::

Pendharkar

City of Residence::

**Dallas** 

State or Province of Residence:: TX

Country of Residence::

US

Street of mailing address::

7575 Frankford Road

Apt. 3223

City of mailing address::

Dallas

State or Province of mailing address::

Postal or Zip Code of mailing address:: 75252

# **Correspondence Information**

Correspondence Customer Number::

23494

TX

### Representative Information

Representative Customer Number::

23494

### **Assignee Information**

Assignee Name:: Texas Instruments Incorporated

Street of mailing address:: 7839 Churchill Way, MS 3999

City of mailing address:: Dallas

State or Province of mailing address:: TX

Country of mailing address:: USA

Postal or Zip Code of mailing address:: 75251